

# MBR1060, MBR1080, MBR1090, MBR10100

MBR1060 and MBR10100 are Preferred Devices

## SWITCHMODE™ Power Rectifiers

This series of SWITCHMODE power rectifiers uses the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

### Features

- Guard-Ring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction
- Pb-Free Packages are Available\*

### Mechanical Characteristics

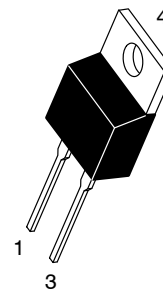
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



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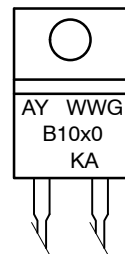
<http://onsemi.com>

## SCHOTTKY BARRIER RECTIFIERS 10 AMPERES, 60 to 100 VOLTS



TO-220AC  
CASE 221B  
PLASTIC

### MARKING DIAGRAM



A = Assembly Location  
Y = Year  
WW = Work Week  
G = Pb-Free Package  
B10x0 = Device Code  
x = 6, 8, 9 or 10  
KA = Diode Polarity

### ORDERING INFORMATION

Device	Package	Shipping
MBR1060	TO-220	50 Units/Rail
MBR1060G	TO-220 (Pb-Free)	50 Units/Rail
MBR1080	TO-220	50 Units/Rail
MBR1080G	TO-220 (Pb-Free)	50 Units/Rail
MBR1090	TO-220	50 Units/Rail
MBR1090G	TO-220 (Pb-Free)	50 Units/Rail
MBR10100	TO-220	50 Units/Rail
MBR10100G	TO-220 (Pb-Free)	50 Units/Rail

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**Preferred** devices are recommended choices for future use and best overall value.

# MBR1060, MBR1080, MBR1090, MBR10100

## MAXIMUM RATINGS

Rating	Symbol	MBR				Unit
		1060	1080	1090	10100	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	60	80	90	100	V
Average Rectified Forward Current (Rated $V_R$ ) $T_C = 133^\circ\text{C}$	$I_{F(AV)}$	10				A
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20 kHz) $T_C = 133^\circ\text{C}$	$I_{FRM}$	20				A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	$I_{FSM}$	150				A
Peak Repetitive Reverse Surge Current (2.0 $\mu\text{s}$ , 1.0 kHz)	$I_{RRM}$	0.5				A
Operating Junction Temperature (Note 1)	$T_J$	- 65 to +175				$^\circ\text{C}$
Storage Temperature	$T_{stg}$	- 65 to +175				$^\circ\text{C}$
Voltage Rate of Change (Rated $V_R$ )	$dv/dt$	10,000				V/ $\mu\text{s}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

## THERMAL CHARACTERISTICS

Maximum Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.0	$^\circ\text{C/W}$
Maximum Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	60	$^\circ\text{C/W}$

## ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 2) ( $i_F = 10$ Amps, $T_C = 125^\circ\text{C}$ ) ( $i_F = 10$ Amps, $T_C = 25^\circ\text{C}$ ) ( $i_F = 20$ Amps, $T_C = 125^\circ\text{C}$ ) ( $i_F = 20$ Amps, $T_C = 25^\circ\text{C}$ )	$v_F$	0.7 0.8 0.85 0.95	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_C = 125^\circ\text{C}$ ) (Rated dc Voltage, $T_C = 125^\circ\text{C}$ – MBR1060 only) (Rated dc Voltage, $T_C = 25^\circ\text{C}$ )	$i_R$	6.0 15 0.10	mA

2. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

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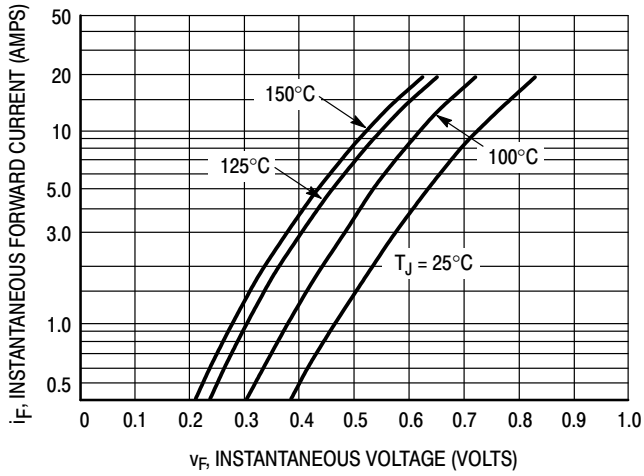


Figure 1. Typical Forward Voltage

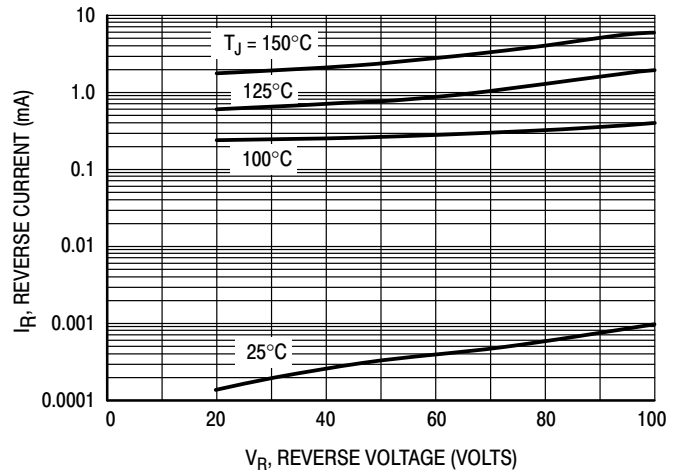


Figure 2. Typical Reverse Current

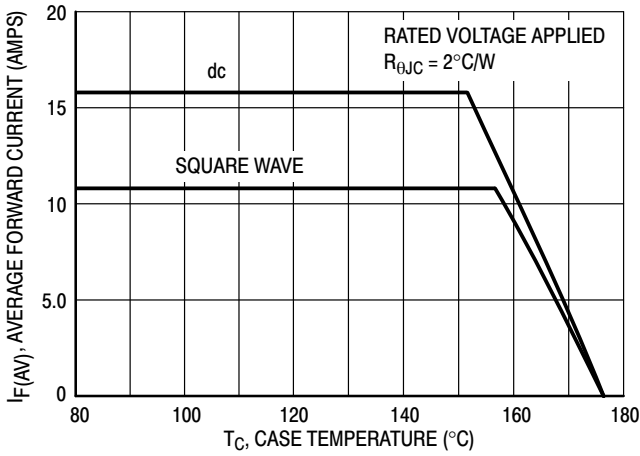


Figure 3. Typical Current Derating, Case

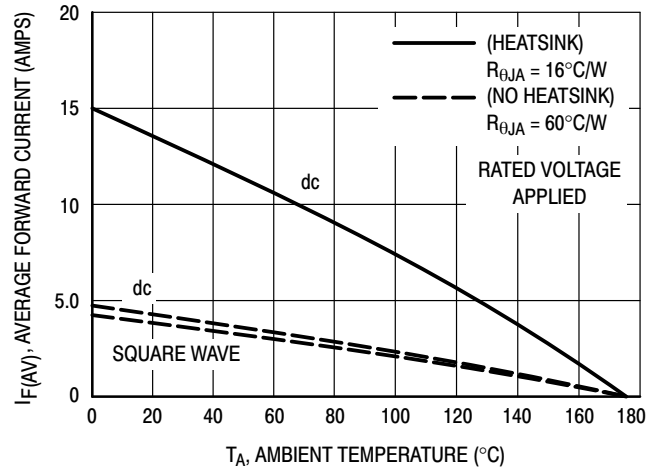


Figure 4. Typical Current Derating, Ambient

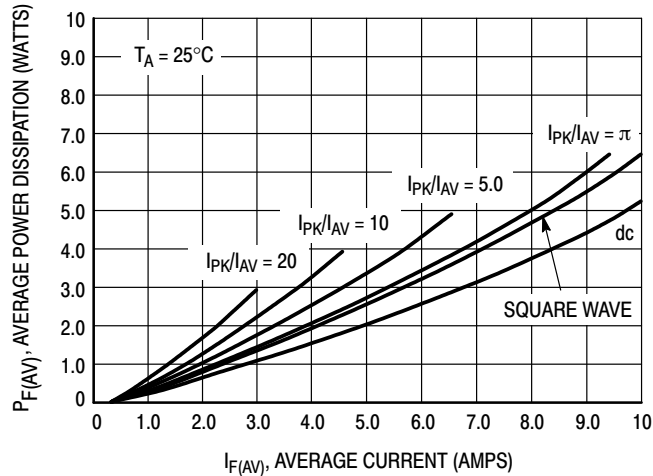
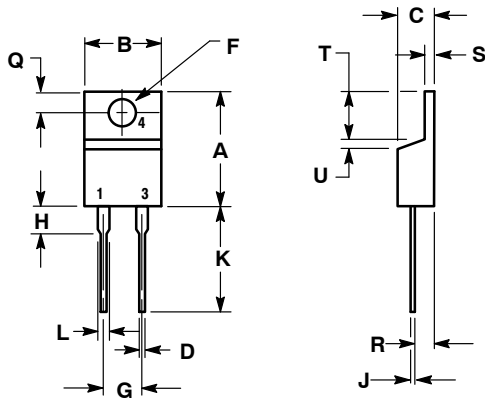


Figure 5. Forward Power Dissipation

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## PACKAGE DIMENSIONS

TO-220  
CASE 221B-04  
ISSUE E




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.595	0.620	15.11	15.75
B	0.380	0.405	9.65	10.29
C	0.160	0.190	4.06	4.82
D	0.025	0.035	0.64	0.89
F	0.142	0.161	3.61	4.09
G	0.190	0.210	4.83	5.33
H	0.110	0.130	2.79	3.30
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
T	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

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**MBR1060/D**